VS-EBU15006HN4

Vishay Semiconductors





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PowerTab[®]

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	150 A				
V _R	600 V				
V _F at I _F	1.08 V				
I _{FSM}	1200 A				
t _{rr} (typ.)	50 ns				
T _J max.	175 °C				
Snap factor	0.5				
Package	PowerTab [®]				
Circuit configuration	Single				

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- · Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

MECHANICAL DATA

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating Terminal: nickel plated, screwable

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Cathode to anode voltage	V _R		600	V			
Continuous forward current	I _{F(AV)}	T _C = 89 °C	150	٨			
Single pulse forward current	I _{FSM}	$T_{C} = 25 \ ^{\circ}C$	1200	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 200 μA		-	-		
		I _F = 150 A	-	1.27	1.63	v	
Forward voltage	V _F	I _F = 150 A, T _J = 125 °C	-	1.15	1.43		
		I _F = 150 A, T _J = 175 °C	-	1.08	1.32		
Deverse leckage current		$V_{R} = V_{R}$ rated	-	-	8	μA	
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	0.5	mA	
Junction capacitance	CT	V _R = 600 V - 7		70	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body - 3.5 - r		nH			









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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CON	IDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \ dI_F/dt = 100 \text{ A}$	A/μs, V _R = 30 V	-	50	-		
Reverse recovery time	+	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ J}$	-	40	-	20		
Reverse recovery time t _{rr}	۲r	T _J = 25 °C		-	100	-	ns	
		T _J = 125 °C		-	210	-		
Poak recovery ourrent		T _J = 25 °C	I _F = 50 A V _B = 200 V	-	10.5	-	А	
Peak recovery current I _{RRM}	T _J = 125 °C	dl _F /dt = 200 V	-	22	-	~		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	550	-	nC	
		T _J = 125 °C		-	2350	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R _{thJC}		-	-	0.35	K/W	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	r\/ vv	
Weight			-	-	5.02	g	
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)	
Marking device		Case style PowerTab®	EBU15006H				

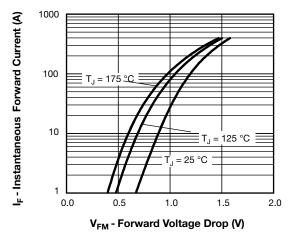


Fig. 1 - Maximum Forward Voltage Drop Characteristics

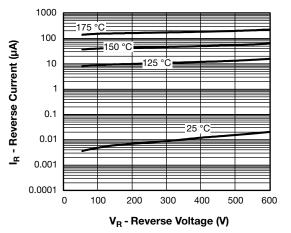
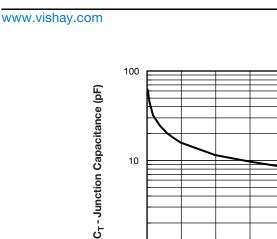


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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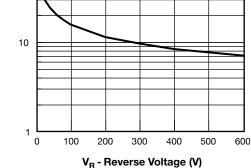


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

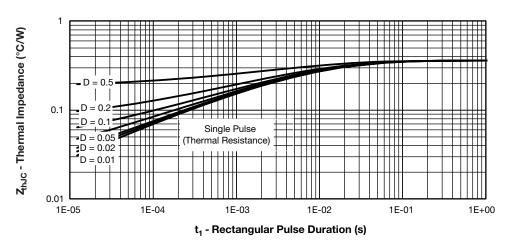


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

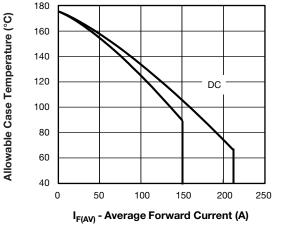


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

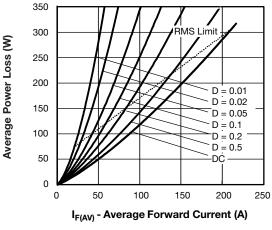


Fig. 6 - Forward Power Loss Characteristics

Revision: 30-Nov-2023

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Document Number: 97197

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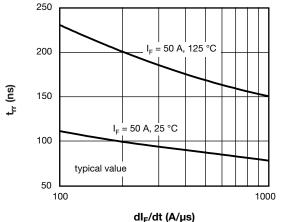


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

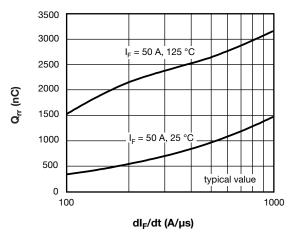


Fig. 8 - Typical Stored Charge vs. dl_F/dt

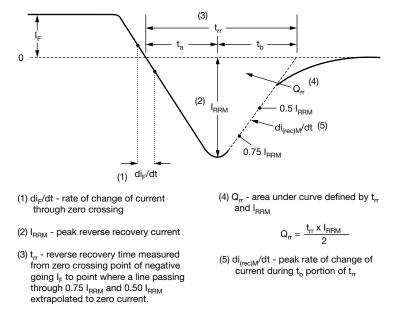


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	Е	В	U	150	06	н	N4
	1	2	3	4	5	6	$\overline{7}$	8
	1	- Visl	nav Sen	niconduc	ctors pro	oduct		
	2.		gle diod					
	3 .	Pov	/erTab [®])				
	4	Ultr	afast re	covery				
	5	- Cur	rent rati	ng (150	= 150 A	A)		
	6	- Volt	age rati	ng (06 =	= 600 V))		
	7.	- H=	AEC-Q	101 qua	lified			
	8	- Env	ironmer	ntal digit	:			
		N4	= halog	en-free,	RoHS-o	compliar	nt, and to	otally le

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-EBU15006HN4	25/tube	Antistatic plastic tube			

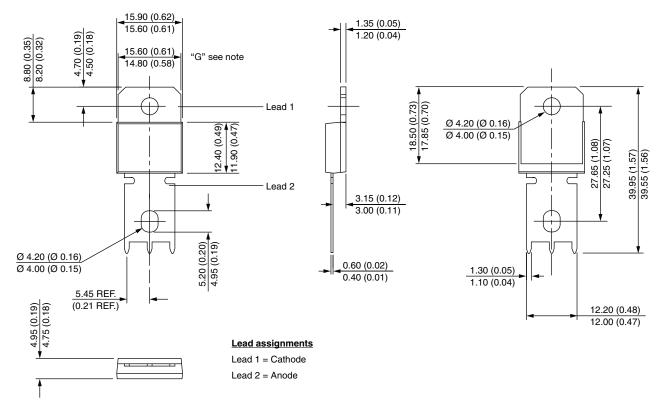
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467				
Application note	www.vishay.com/doc?95179				
SPICE model	www.vishay.com/doc?97099				



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DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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Revision: 01-Jan-2025

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